

120V N-Ch Power MOSFET

V_{DS} 120 V
 $R_{DS(on),typ}$ $V_{GS}=10V$ 20.0 m
 $R_{DS(on),typ}$ $V_{GS}=4.5V$
 I_D (Silicon Limited)

| | | | |
|-----------------------------------|----------------|---------------------------|---|
| Gate to Source Voltage | V_{GS} | - | |
| Power Dissipation | P_D | $L=0.1mH, T_C=5^{\circ}C$ | 5 |
| Operating and Storage Temperature | T_J, T_{stg} | $T_C=5^{\circ}C$ | - |

| Absolute Maximum Ratings | |
|----------------------------------|----------|
| Parameter | Value |
| Thermal Resistance Junction-Lead | R_{JL} |

SJEnoneMax
Max
23
40

Unit
÷ ● %

Electrical Characteristics at $T_J=5^\circ C$ -
a aa !
Static Characteristics

| Parameter | Symbol | Conditions | Value | | | Unit |
|-----------------------------------|---------------|--|-------|-----|-----|------|
| | | | min | typ | max | |
| Drain to Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=250A$ | 120 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{GS}=V_{DS}, I_D=250A$ | 1.4 | 2.0 | 2.4 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS}=0V, V_{DS}=120V, T_J=5^\circ C$ | - | - | 1 | A |
| | | $V_{GS}=0V, V_{DS}=120V, T_J=50^\circ C$ | - | - | 100 | |
| Gate to Source Leakage Current | I_{GSS} | $V_{GS}=5V, V_{DS}=0V$ | - | - | 100 | nA |
| Drain to Source on Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=5A$ | - | 20 | 25 | m |
| Drain to Source on Resistance | $R_{DS(on)}$ | $V_{GS}=4.5V, I_D=5A$ | - | 25 | 31 | m |
| Transconductance | g_{fs} | $V_{DS}=5V, I_D=5A$ | - | 20 | - | S |
| Gate Resistance | R_G | $V_{GS}=0V, V_{DS} \text{ Open}, f=1MHz$ | - | 8.5 | - | |

Dynamic Characteristics

| | | | | | | |
|-------------------------------|--------------|--|---|------|---|----|
| Input Capacitance | C_{iss} | $V_{GS}=0V, V_{DS}=60V, f=1MHz$ | - | 977 | - | pF |
| Output Capacitance | C_{oss} | | - | 143 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 6.2 | - | |
| Total Gate Charge | $Q_g(10V)$ | $V_{DD}=60V, I_D=5A, V_{GS}=10V$ | - | 13.5 | - | nC |
| Total Gate Charge | $Q_g(4.5V)$ | | - | 7.6 | - | |
| Gate to Source Charge | Q_{gs} | | - | 2.8 | - | |
| Gate to Drain (Miller) Charge | Q_{gd} | | - | 2.0 | - | |
| Turn on Delay Time | $t_{d(on)}$ | | - | 8 | - | ns |
| Rise time | t_r | $V_{DD}=60V, I_D=5A, V_{GS}=10V, R_G=10\Omega$ | - | 8 | - | |
| Turn off Delay Time | $t_{d(off)}$ | | - | 14 | - | |
| Fall Time | t_f | | - | 9 | - | |

Reverse Diode Characteristics

| | | | | | | |
|-------------------------|----------|-----------------------------------|---|-----|-----|----|
| Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_F=20A$ | - | 0.9 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $V_R=60V, I_F=5A, dI_F/dt=500A/s$ | - | 25 | - | ns |
| Reverse Recovery Charge | Q_{rr} | | - | 91 | - | nC |

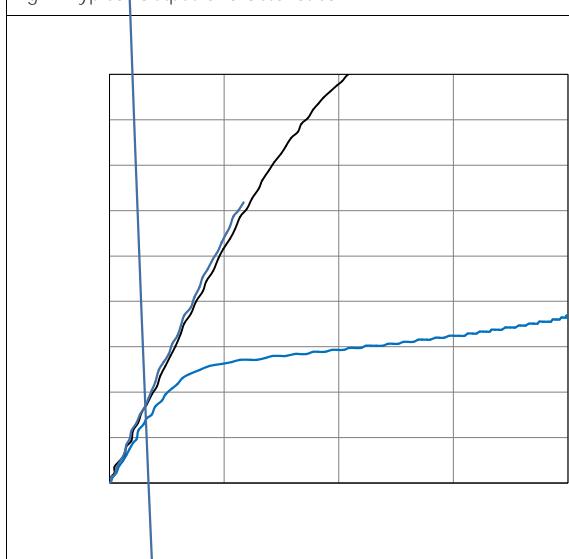
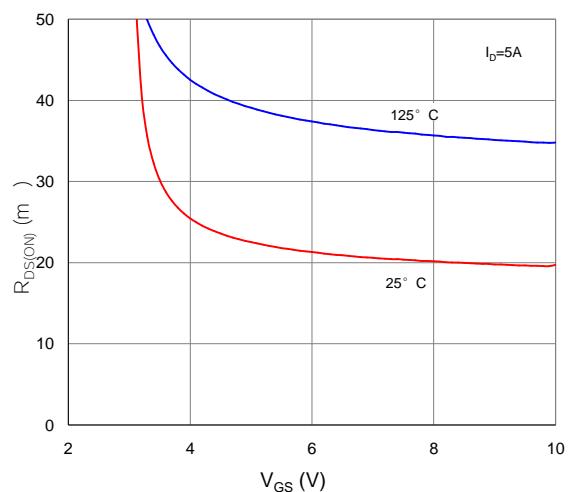
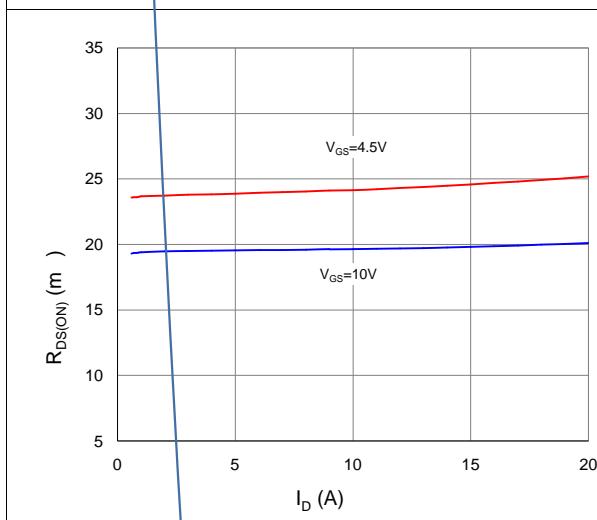
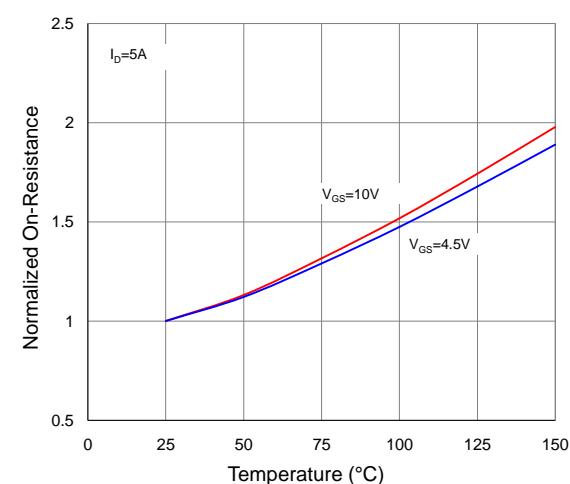
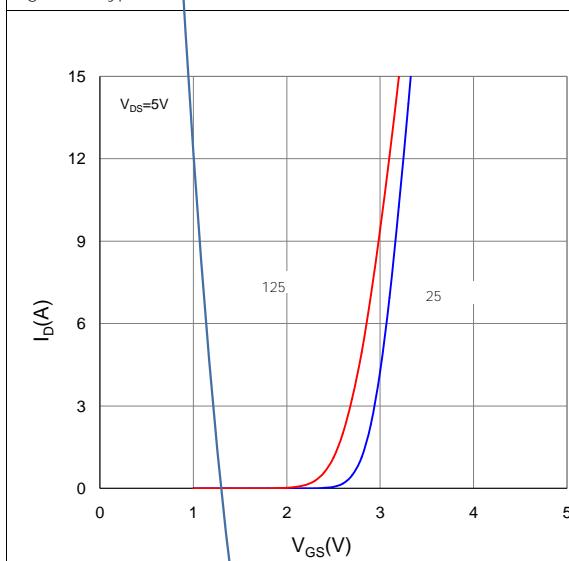
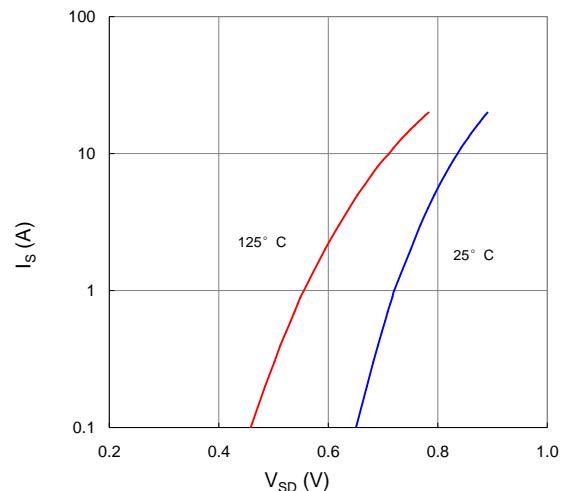
Fig 1. Typical Output Characteristics

Figure 2. On-Resistance vs. Gate-Source Voltage

Figure 3. On-Resistance vs. Drain Current and Gate Voltage

Figure 4. Normalized On-Resistance vs. Junction Temperature

Figure 5. Typical Transfer Characteristics

Figure 6. Typical Source-Drain Diode Forward Voltage


Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage



Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

Figure 9. Maximum Safe Operating Area

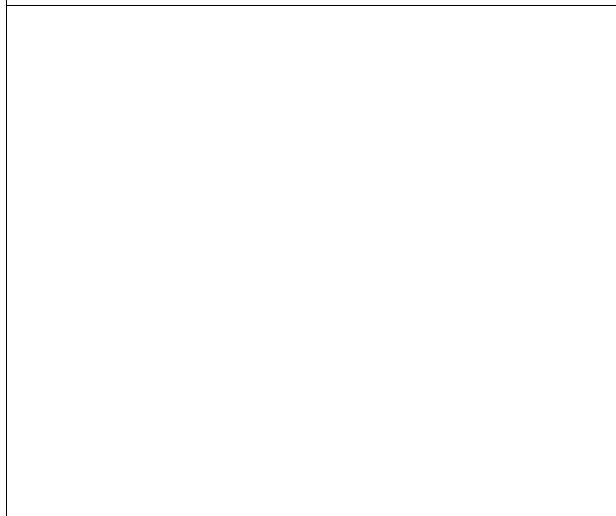
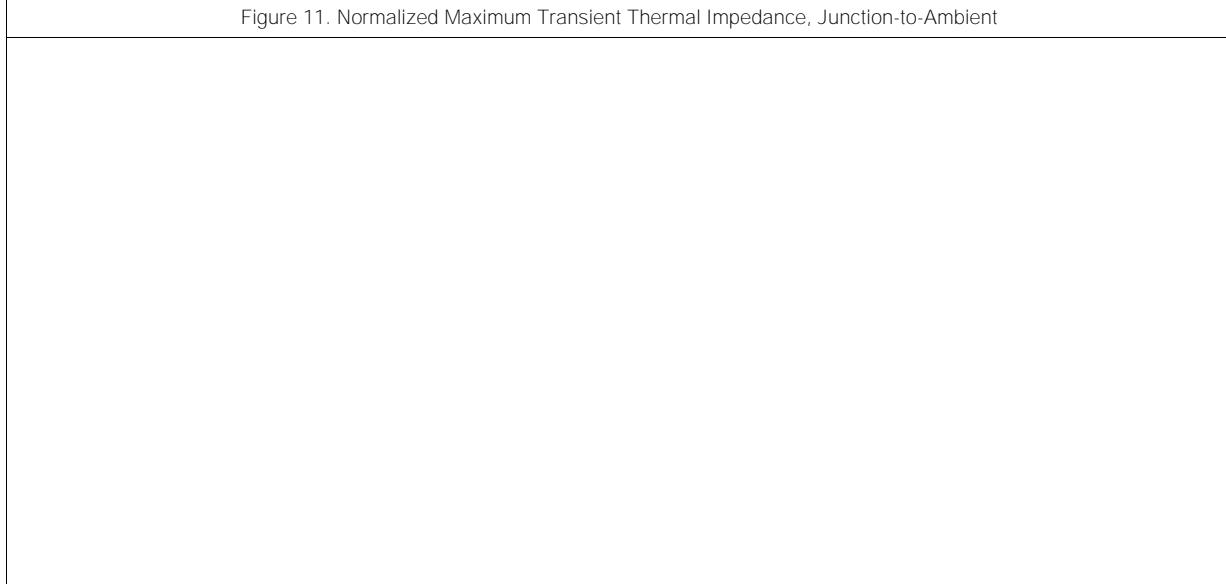
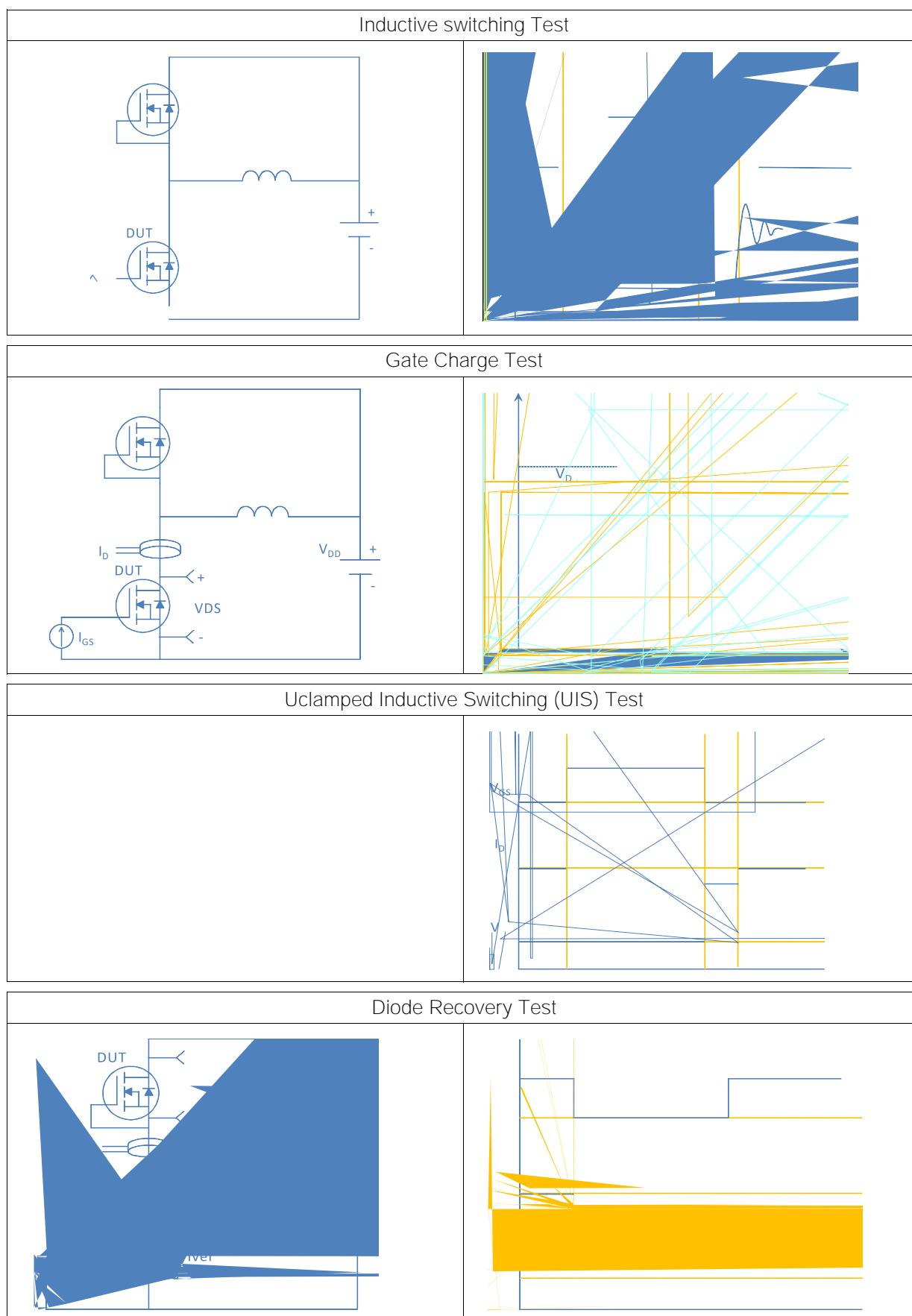


Figure 10. Maximum Drain Current vs. Case Temperature

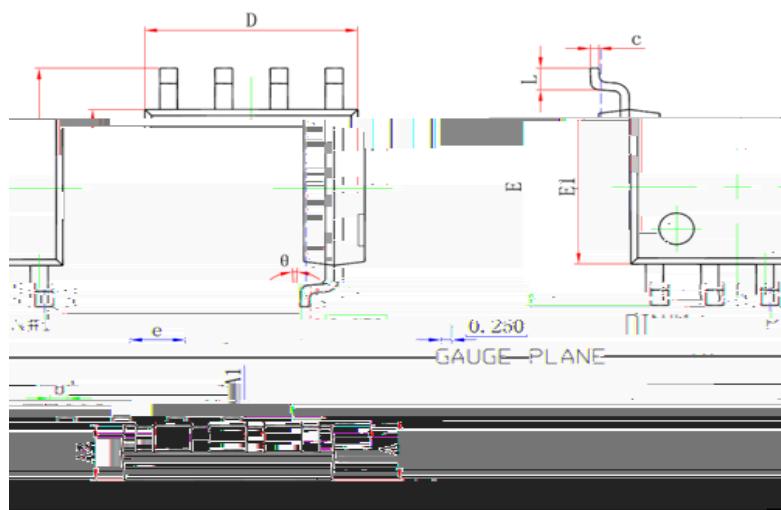
Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Ambient





Package Outline

SOIC-8, 8 leads



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.250 | 1.650 | 0.049 | 0.065 |
| b | 0.310 | 0.510 | 0.012 | 0.020 |
| c | 0.170 | 0.250 | 0.007 | 0.010 |
| D | 4.800 | 5.000 | 0.189 | 0.197 |
| e | 1.270 (BSC) | | 0.050 (SBC) | |
| E | 5.800 | 6.200 | 0.228 | 0.244 |
| E1 | 3.800 | 4.000 | 0.150 | 0.157 |
| L | 0.400 | 1.270 | 0.016 | 0.031 |
| θ | 0° | 8° | 0° | 8° |